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ATTORNEY DOCKET NO. 04156.0022U1 EXPRESS MAIL LABEL NO.EL 997678790 US PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of				
NÄGEL, Wulf	Art Unit:			
International Application No. PCT/EP2004/010916	Examiner:			
International Filing Date: 30 September 2004	Confirmation No.			
For: PHOTOVOLTAIC ELEMENT)			

INFORMATION DISCLOSURE STATEMENT

Mail Stop PCT Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

NEEDLE & ROSENBERG, P.C. Customer Number 23859

Sir:

Pursuant to the requirements of 37 C.F.R. § 1.56, submitted herewith on the accompanying Information Disclosure Statement List is a listing of documents known to Applicants and/or their attorneys. In accordance with 37 C.F.R. §1.98(a)(2), copies of any cited U.S. patent or U.S. patent application publication documents are not enclosed. Copies of any cited foreign patent document and/or any non-patent publication are enclosed.

This Information Disclosure Statement is believed to be filed in a timely manner pursuant to 37 C.F.R. § 1.97(b)(3), in that a first Office Action on the merits of the present patent application has not yet been mailed to Applicants.

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Consideration of the cited documents and making the same of record in the prosecution of the above-referenced application are respectfully requested.

No fee is believed to be due; however, the Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to Deposit Account No. 14-0629.

Respectfully submitted,

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ATTORNEY DOCKET NO. 04156.0022U1 EXPRESS MAIL LABEL NO. EL 997678790 US INTERNATIONAL APPLICATION NO. PCT/GB2004/010916 SHEET 1 OF 1

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